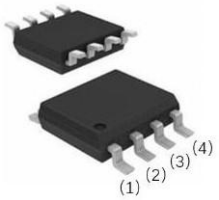
P61089B **http://www.wdsemi.com**

High Voltage Ringing SLIC Protector

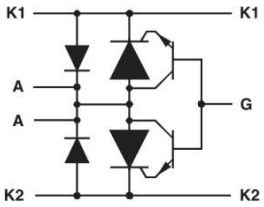
Waveshape	I_{PPSM}
5/320μs	50A
10/1000μs	40A
1.2/50μs	120A

Descriptions

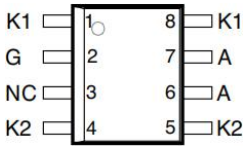
This device is especially designed to protect Subscriber Line Interface Circuit (SLIC) against transient overvoltage. Positive overloads are clipped with 2 diodes. Negative surges are suppressed by 2 Thyristors, their breakdown voltage being referenced to VBAT through the gate. This component presents a very low gate triggering current and minimizes overvoltage stress on the SLIC.



SOP-8L



Package & Device Symbol

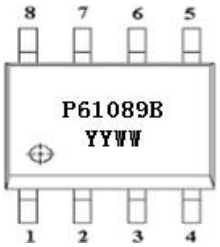


Pin configuration (Top view)

Features

- Dual programmable transient suppressor
- Wide battery voltage supports
- Low gate triggering current
- High holding current.
- MSL: Level 3

Pin	Pin Name	Description
1，8	K1	Connect to subscriber lines (Tip/Ring)
4，5	K2	
2	G	Connect to battery (Reference Voltage)
6，7	A	Connect to ground
3	NC	Not connected



P61089B = Device Code
Y = Special Code
Y =Year
WW =Week

Marking

Applications

- Switch Line Card
- Access Network Line Card
- PBX
- VoIP

Order information

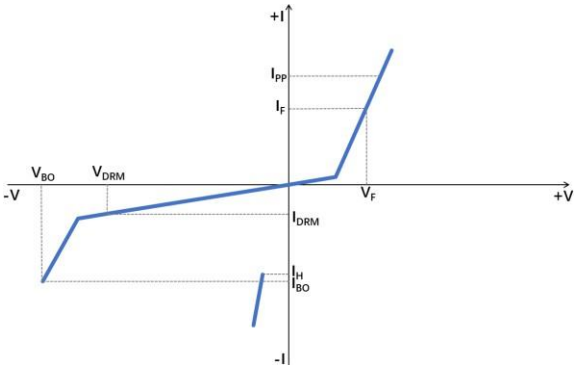
Device	Package	Shipping
P61089B	SOP-8L	4000/Reel&Tape

Absolute Maximum ratings

Parameter		Symbol	Value	Unit
Non-repetitive peak on-state pulse current	10/1000μs (Telcordia (Bellcore) GR-1089-CORE, Issue 2, February 1999, Section 4)	I_{PPSM}	40	A
	5/320μs (ITU-T K.20, K.21& K.45, K.44 open-circuit voltage wave shape 10/700 μs)		50	
	1.2/50μs (Telcordia (Bellcore) GR-1089-CORE, Issue 2, February 1999, Section 4)		120	
Non repetitive peak on-state current (sinusoidal) 60Hz	0.5s	I_{TSM}	6.5	A
	1s		4.5	
	5s		2.4	
	30s		1.3	
	900s		0.72	
Repetitive peak off-state voltage, V_{GK}=0		V_{DRM}	-170	V
Repetitive peak gate-cathode voltage, V_{KA}=0		V_{GKRM}	-167	V
Operating free-air temperature range		T_A	-40-85	°C
Storage temperature range		T_{STG}	-40-150	°C
Junction temperature		T_J	-40-150	°C
Maximum lead temperature for soldering during 10s		T_L	260	°C
Junction to free air thermal resistance		$R_{\theta JA}$	120	°C /W

Parameter Measurement Information

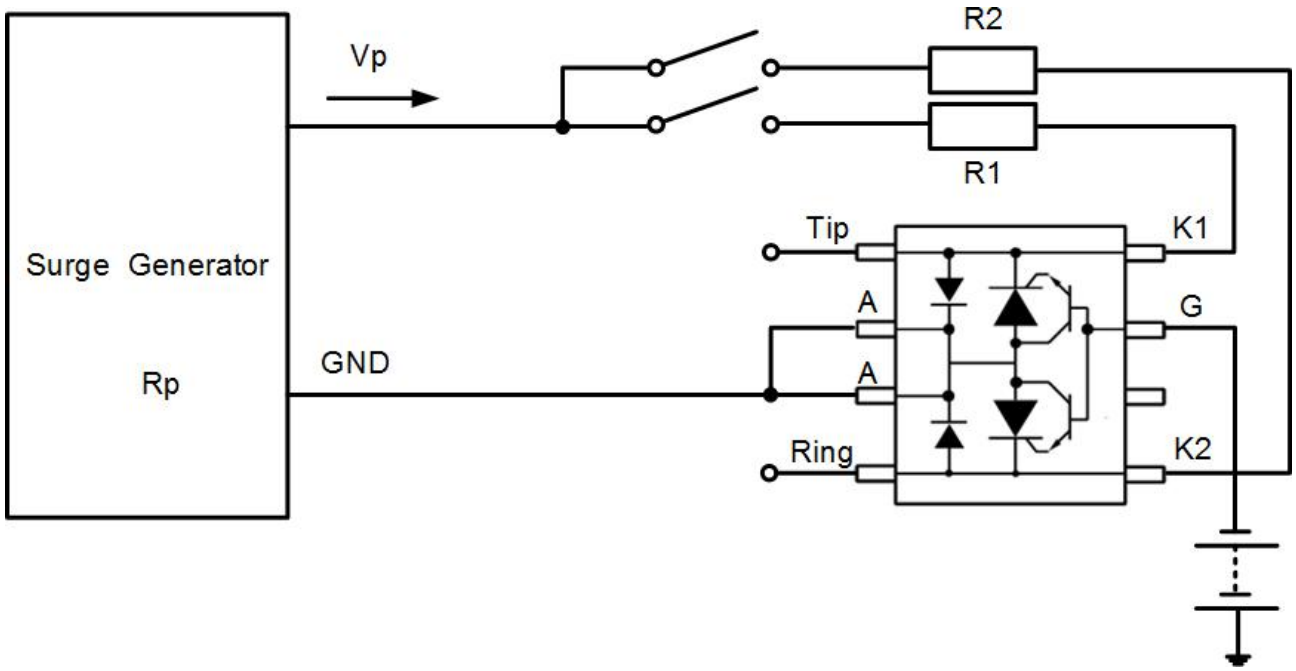
Parameter	Symbol
Off-state current	I_{DRM}
Holding current	I_H
Breakover voltage	$V_{(BO)}$
Forward voltage	V_F
Peak forward recovery voltage	V_{FRM}
Gate-cathode impulse breakover voltage	$V_{GK(BD)}$
Gate reverse current	I_{GKS}
Gate trigger current	I_{GT}
Gate-cathode trigger voltage	V_{GT}
Cathode-anode off-state capacitance	C_{KA}



Electronics Characteristics (Ta=25ºC, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward voltage	V_F	I_F=5A, t_W=200μs			3	V
Impulse peak forward recovery voltage	V_{FRM}	2/10us, I_F=100A, R_S=50Ω, di/dt=80A/us			10	V
Off-state current	I_D	V_D= -170V, V_{GK}=0, T_J = 25 °C			-5	uA
		V_D= -170V, V_{GK}=0, T_J = 85 °C				
Impulse breakover voltage	$V_{(BO)}$	2/10us, I_{TM}=100A, R_S=50Ω di/dt=-80A/us, V_{GG}=-100V			-112	V
Holding current	I_H	I_T=-1A, di/dt=1A/ms, V_{GG}=-100V	-150			mA
Gate reverse current	I_{GAS}	V_{GG}=V_{GK}= -167V, V_{KA}=0, T_J = 25 °C			-5	uA
		V_{GG}=V_{GK}= -167V, V_{KA}=0, T_J = 85 °C				
Gate trigger current	I_{GT}	V_{AK}=40V, Value=3.5V, t_W=10ms			5	mA
Gate trigger voltage	V_{GT}	V_{AK}=40V, Value=3.5V, t_W=10ms			2.5	V
Anode-cathode offstate capacitance	C_{KA}	f=1MHz,V_D=1V, I_G=0, V_D=-3V			110	pF
		f=1MHz,V_D=1V, I_G=0, V_D=-48V			55	

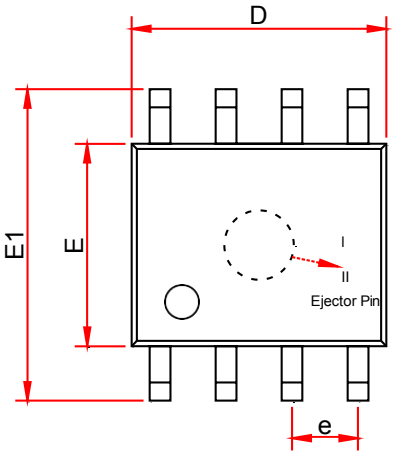
Surge Test Circuit



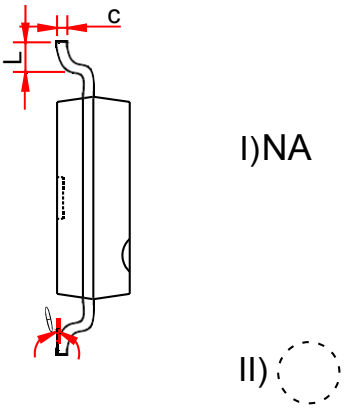
Pulse(μs)		Vp(V)	Ipp(A)	Rp(Ω)	R1(Ω)	R2(Ω)
T_{rise}	T_{fall}					
10	700	±2000	±50	40	0	0
10	1000	±400	±40	10	0	0
1.2	50	±5000	±120	2	40	40

Package Outline Dimensions

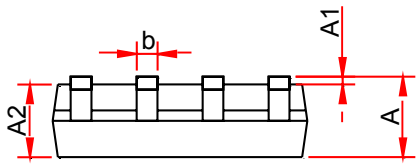
SOP-8L



TOP VIEW



SIDE VIEW

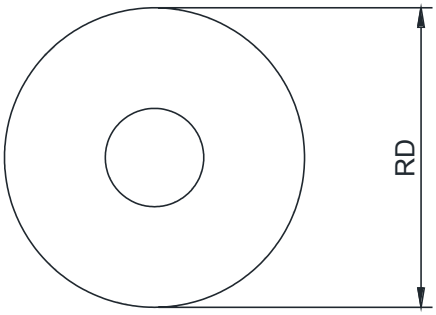


SIDE VIEW

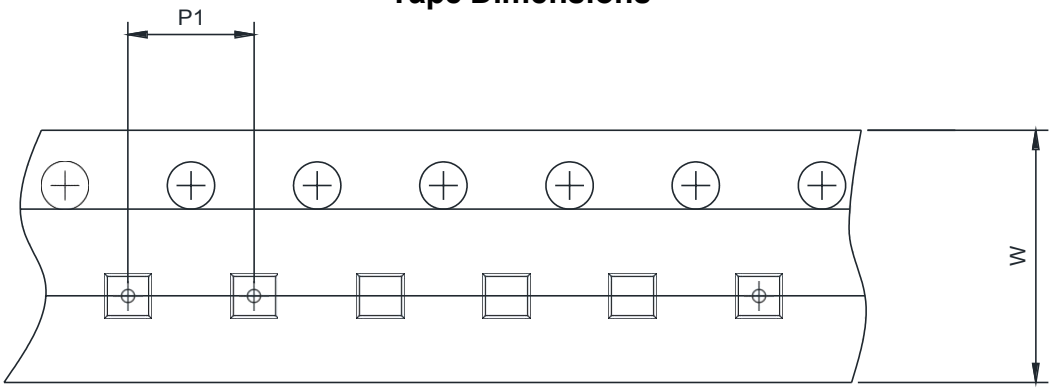
Symbol	Dimensions In Millimeters (mm)		
	Min.	Typ.	Max.
A	1.35	1.55	1.75
A1	0.05	0.15	0.25
A2	1.25	1.40	1.65
b	0.33	-	0.51
c	0.15	-	0.26
D	4.70	4.90	5.10
E	3.70	3.90	4.10
E1	5.80	6.00	6.20
e	1.27BSC		
L	0.40	-	1.27
θ	0°	-	8°

Tape and Reel Information

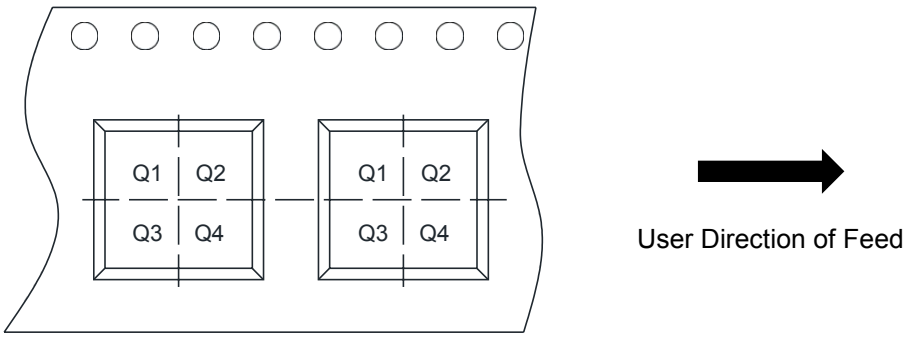
Reel Dimensions



Tape Dimensions



Quadrant Assignments For PIN1 Orientation In Tape



RD	Reel Dimension	☐ 7inch	☑ 13inch		
W	Overall width of the carrier tape	☐ 8mm	☑ 12mm		
P1	Pitch between successive cavity centers	☐ 2mm	☐ 4mm	☑ 8mm	
Pin1	Pin1 Quadrant	☑ Q1	☐ Q2	☐ Q3	☐ Q4